

GENERAL PURPOSE APPLICATION.
SWITCHING APPLICATION .

FEATURES

- High Voltage : BC846W $V_{CEO}=65V$.
- For Complementary With PNP Type BC856W/857W/858W.

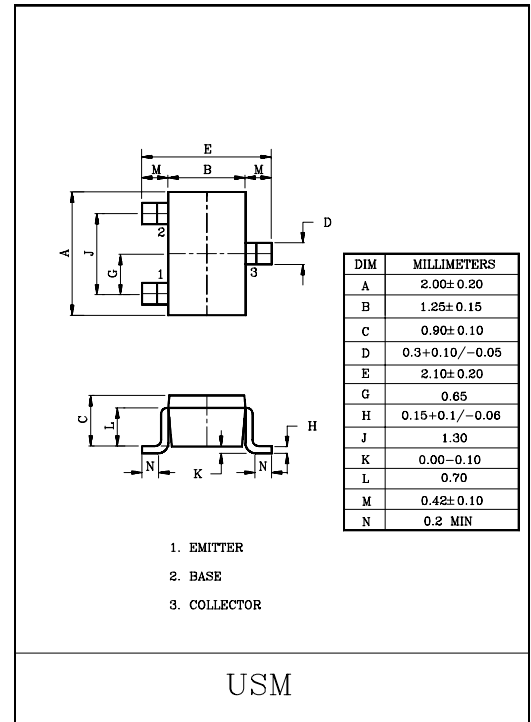
MAXIMUM RATINGS ($T_a=25^{\circ}C$)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage	BC846W	V_{CBO}	80	V
	BC847W		50	
	BC848W		30	
Collector-Emitter Voltage	BC846W	V_{CEO}	65	V
	BC847W		45	
	BC848W		30	
Emitter-Base Voltage	BC846W	V_{EBO}	6	V
	BC847W		6	
	BC848W		5	
Collector Current		I_C	100	mA
Emitter Current		I_E	-100	mA
Collector Power Dissipation		P_C *	100	mW
Junction Temperature		T_j	150	$^{\circ}C$
Storage Temperature Range		T_{stg}	-55~150	$^{\circ}C$

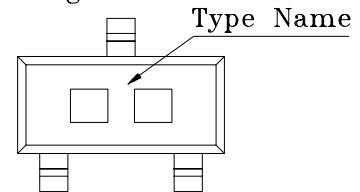
P_C * : Package Mounted On 99.5% Alumina $10 \times 8 \times 0.6mm$.

MARK SPEC

TYPE	BC846AW	BC846BW	BC847AW	BC847BW	BC847CW	BC848AW	BC848BW	BC848CW
MARK	1A	1B	1E	1F	1G	1J	1K	1L



Marking



BC846W/7W/8W

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I_{CBO}	$V_{CB}=30V, I_E=0$	–	–	15	nA
DC Current Gain (Note)	BC846W	h_{FE}	$V_{CE}=5V, I_C=2mA$	110	–	450	
	BC847W			110	–	800	
	BC848W			110	–	800	
Collector-Emitter Saturation Voltage		$V_{CE(sat) 1}$	$I_C=10mA, I_B=0.5mA$	–	0.09	0.25	V
		$V_{CE(sat) 2}$	$I_C=100mA, I_B=5mA$	–	0.2	0.6	
Base-Emitter Saturation Voltage		$V_{BE(sat) 1}$	$I_C=10mA, I_B=0.5mA$	–	0.7	–	V
		$V_{BE(sat) 2}$	$I_C=100mA, I_B=5mA$	–	0.9	–	
Base-Emitter Voltage		$V_{BE(ON1)}$	$V_{CE}=5V, I_C=2mA$	0.58	–	0.7	V
		$V_{BE(ON2)}$	$V_{CE}=5V, I_C=10mA$	–	–	0.75	V
Transition Frequency		f_T	$V_{CE}=5V, I_C=10mA, f=100MHz$	–	300	–	MHz
Collector Output Capacitance		C_{ob}	$V_{CB}=10V, f=1MHz$	–	2.5	4.5	pF
Noise Figure		NF	$V_{CE}=6V, I_C=0.1mA, R_g=10k\Omega, f=1kHz$	–	1.0	10	dB

NOTE : According to the value of h_{FE} the BC846W, BC847W, BC848W are classified as follows.

CLASSIFICATION		A	B	C
h_{FE}	BC846W	110~220	200~450	–
	BC847W	110~220	200~450	420~800
	BC848W	110~220	200~450	420~800

BC846W/7W/8W

